

# Wladimir Marine

## List of Publications by Year in descending order

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41  
papers

1,332  
citations

411340

20  
h-index

388640

36  
g-index

41  
all docs

41  
docs citations

41  
times ranked

1390  
citing authors

#	ARTICLE	IF	CITATIONS
1	Cuprous oxide thin films prepared by thermal oxidation of copper layer. Morphological and optical properties. <i>Journal of Luminescence</i> , 2015, 159, 325-332.	1.5	24
2	Impacts of Ambient and Ablation Plasmas on Short- and Ultrashort-Pulse Laser Processing of Surfaces. <i>Micromachines</i> , 2014, 5, 1344-1372.	1.4	29
3	Substituted dibenzo[2,3:5,6]-pyrrolizino[1,7-bc]indolo[1,2,3-lm]carbazoles: a series of new electron donors. <i>Tetrahedron</i> , 2013, 69, 3302-3307.	1.0	15
4	Non-linear absorption of focused femtosecond laser pulses at 1.3 $\mu$ m inside silicon: Independence on doping concentration. <i>Applied Surface Science</i> , 2013, 278, 13-18.	3.1	21
5	Synthesis and spectroscopic properties of 4-amino-1,8-naphthalimide derivatives involving the carboxylic group: a new molecular probe for ZnO nanoparticles with unusual fluorescence features. <i>Beilstein Journal of Organic Chemistry</i> , 2013, 9, 1311-1318.	1.3	19
6	Non-linear absorption of 1.3 $\mu$ m wavelength femtosecond laser pulses focused inside semiconductors: Finite difference time domain-two temperature model combined computational study. <i>Journal of Applied Physics</i> , 2011, 110, .	1.1	18
7	Properties of nano-structured cuprous oxide thin films fabricated by thermal oxidation of copper layer. <i>Proceedings of SPIE</i> , 2011, , .	0.8	1
8	Cluster Generation Under Pulsed Laser Ablation Of Compound Semiconductors. <i>AIP Conference Proceedings</i> , 2010, , .	0.3	6
9	Dibenzo[2,3:5,6]pyrrolizino[1,7-bc]indolo[1,2,3-lm]carbazole: a new electron donor. <i>New Journal of Chemistry</i> , 2010, 34, 1243.	1.4	18
10	Quantum Size Effect and very localized random laser in ZnO@mesoporous silica nanocomposite following a two-photon absorption process. <i>Journal of Non-Crystalline Solids</i> , 2009, 355, 1152-1156.	1.5	6
11	Random laser action of ZnO@mesoporous silicas. <i>Nanotechnology</i> , 2008, 19, 105710.	1.3	19
12	Picosecond laser structuration under high pressures: Observation of boron nitride nanorods. <i>Journal of Applied Physics</i> , 2008, 104, .	1.1	6
13	Insight into electronic mechanisms of nanosecond-laser ablation of silicon. <i>Journal of Applied Physics</i> , 2008, 103, .	1.1	34
14	ZnO/mesoporous silica nanocomposites prepared by the reverse micelle and the colloidal methods: Photoluminescent properties and quantum size effect. <i>Chemical Physics Letters</i> , 2007, 438, 67-71.	1.2	36
15	Synthesis of nanoclusters by nanosecond laser ablation: Direct simulation Monte Carlo modelling. <i>Applied Surface Science</i> , 2006, 252, 4433-4438.	3.1	21
16	Incorporation of cobalt into ZnO nanoclusters. <i>Materials Science and Engineering C</i> , 2005, 25, 614-617.	3.8	25
17	A general continuum approach to describe fast electronic transport in pulsed laser irradiated materials: the problem of Coulomb explosion. , 2004, , .		4
18	Surface nanostructuring of metals by laser irradiation: effects of pulse duration, wavelength and gas atmosphere. <i>Applied Physics A: Materials Science and Processing</i> , 2004, 79, 1433-1437.	1.1	103

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19	Enhancement of exciton emission from ZnO nanocrystalline films by pulsed laser annealing. Applied Surface Science, 2004, 226, 242-248.	3.1	53
20	Ablation of carbide materials with femtosecond pulses. Applied Surface Science, 2003, 205, 80-85.	3.1	23
21	Laser surface microstructuring to improve tribological systems. , 2003, , .		4
22	<title>Femtosecond laser ablation of materials</title>. , 2003, , .		5
23	Femtosecond ablation of ultrahard materials. Applied Physics A: Materials Science and Processing, 2002, 74, 729-739.	1.1	170
24	Excimer laser decontamination. , 2000, 4071, 196.		1
25	Surface oxide removal by a XeCl laser for decontamination. Quantum Electronics, 2000, 30, 495-500.	0.3	20
26	Modeling of gas dynamics for a laser-generated plasma: Propagation into low-pressure gases. Physical Review E, 2000, 62, 4152-4161.	0.8	72
27	Photoluminescence of silicon nanoclusters with reduced size dispersion produced by laser ablation. Journal of Applied Physics, 2000, 87, 3829-3837.	1.1	217
28	Synthesis and properties of Si and Ge nanoclusters produced by pulsed laser ablation. Applied Physics A: Materials Science and Processing, 1999, 69, S217-S221.	1.1	9
29	Size dependent photoluminescence from Si nanoclusters produced by laser ablation. Journal of Luminescence, 1998, 80, 217-221.	1.5	27
30	Experimental study of spontaneous electric field generated by a laser plasma. Applied Physics Letters, 1998, 73, 25-27.	1.5	50
31	Electric fields of a laser plasma formed by optical breakdown of air near various targets. Quantum Electronics, 1998, 28, 24-28.	0.3	14
32	Luminescence from a Si-SiO <sub>2</sub> nanocluster-like structure prepared by laser ablation. Thin Solid Films, 1995, 255, 286-289.	0.8	73
33	â€œCleanâ€™â€™ processing of polymers and smoothing of ceramics by pulsed laser melting. Journal of Applied Physics, 1995, 77, 4714-4723.	1.1	22
34	Analytical thermal model of ultraviolet laser ablation with single-photon absorption in the plume. Journal of Applied Physics, 1995, 78, 1241-1246.	1.1	53
35	Shock wave and plasma dynamics in a surface discharge flash lamp. Applied Physics Letters, 1994, 65, 1626-1628.	1.5	7
36	Ablation dynamics of silicon based targets in oxygen and nitrogen atmospheres. Thin Solid Films, 1994, 241, 103-108.	0.8	38

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37	Time-resolved measurements of plume shielding during ArF laser ablation of silicon. Thin Solid Films, 1994, 241, 129-133.	0.8	10
38	VUV light production from a formed-ferrite plasma source. Applied Surface Science, 1993, 69, 185-192.	3.1	7
39	Emission spectra analyses of a new vacuum ultraviolet source. Applied Physics Letters, 1993, 63, 2333-2335.	1.5	10
40	Microstructure of $Y_{1-x}Ba_xCu_{1-y}O$ superconducting thin films deposited by high power and high repetition rate excimer lasers. Materials Science and Engineering B: Solid-State Materials for Advanced Technology, 1992, 14, 134-141.	1.7	0
41	Analysis of the plasma expansion dynamics by optical time-of-flight measurements. Applied Surface Science, 1992, 54, 264-270.	3.1	42